

Specifications are subject to change without notice.

**DESCRIPTION**

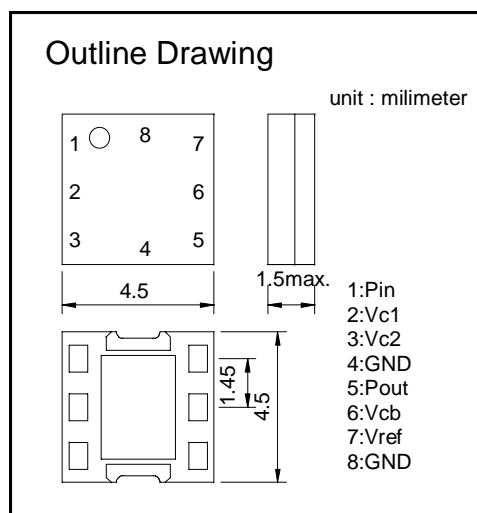
The BA01207 GaAs RF amplifier designed for J-cdmaOne hand-held phone.

**FEATURES**

- Low voltage Vc =3.5V
  - High power Po=27.5dBm
  - High gain Gp=27.5dB@Po=27.5dBm
  - 2stage amplifier
  - Internal input\* and output matching
- \*Use DC block for input port

**APPLICATION**

N-CDMA (Spreading chip rate is 1.2288Mcps, modulation is OQPSK) hand set.



**ABSOLUTE MAXIMUM RATINGS (Ta=25°C)**

Symbol	Parameter	Condition	Ratings*	Unit
Vcc	Supply voltage of HPA		6	V
Pin	Input power	ZG=ZL=50Ω	7	dBm
Tc(op)	Operating case temp.		-20 ~ +85	°C
Tstg	Storage temp.		-30 ~ +125	°C

\*Note : Each maximum rating is guaranteed independently .

**ELECTRICAL CHARACTERISTICS(Ta=25° C , ZG=ZL=50Ω)**

Symbol	Parameter	Test conditions	Limits			Unit
			MIN	TYP	MAX	
f	Frequency		887	-	925	MHz
Iq	Quiescent current	Vc=3.5V, Vcb=Vref=2.8V No Signal	-	55	70	mA
Ict <sup>*1</sup>	Total current	Po=27.5dBm (IS-95B)	-	395	420	mA
Icb+Iref	Total current	Vc1=Vc2=3.5V	-	5.3	10	mA
hadd	Power added efficiency	Vcb=Vref=2.8V	-	40	-	%
Gain	Power Gain		25	27.5	-	dB
ACP <sup>*2</sup>	Adjacent channel power at 900KHz		-	-50	-47	dBc
	Adjacent channel power at 1.98MHz		-	-60	-57	dBc
2sp	2nd harmonics		-	-30	-27	dBc
3sp	3rd harmonics		-	-45	-30	dBc
Rxnoise	Noise in RX band		-	-138	-135	dBm/Hz
Ict <sup>*1</sup>	Total current	Po=15dBm (IS-95B)	-	107	122	mA
Icb+Iref	Total current	Vc1=Vc2=1.2V	-	2.5	5.5	mA
Gain	Power Gain	Vcb=Vref=2.8V	21.5	24	-	dB
ACP <sup>*2</sup>	Adjacent channel power at 900KHz		-	-55	-47	dBc
	Adjacent channel power at 1.98MHz		-	-66	-58	dBc

\*1: Ict=Ic1+Ic2, \*2:ACP=ACP (30KHz band at 900/1980KHz)-Po(1.23MHz band)

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